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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet	1	of	5

Complete if Known	
Application Number	10/042,549
Filing Date	January 9, 2002
First Named Inventor	MICHALUK
Art Unit	1742
Examiner Name	Lois L. Zheng
Attorney Docket Number	CPM00029CIP (3600-328-01)

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No.[1]	Document Number Number - Kind Code[2] (*if known*)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		US-6,323,055 B1	11/27/2001	Rosenberg et al.	
		US-6,331,233 B1	12/18/2001	Turner	
		US-6,348,139 B1	02/19/2002	Shah et al.	
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		US-4,844,746	07/04/1989	Hormann et al.	
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FOREIGN PATENT DOCUMENTS

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		JP 1994-264232	09/20/1994	Shimizu et al.		English translation

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LL		LASSILA et al., "Mechanical Behavior of Tantalum and Tantalum-Tungsten Alloys: Texture Gradients and Macro/Micro-Response," 14TH U.S. ARMY SYMPOSIUM ON SOLID MECHANICS, November 30, 1996 (14 pgs.)	
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